TOSHIBA Photocoupler GaAs Ired & Photo-Triac

TLP3502A

Trica Driver Programmable Controllers AC-Output Module Solid State Relay

查询TLP3502A供应商 **TOSHIBA**

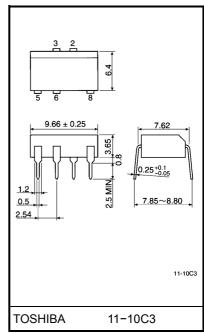
The TOSHIBA TLP3502A consists of a photo–triac optically coupled to a gallium arsenide infrared emitting diode in a 8 lead plastic DIP package.

- Peak off-state voltage: 400V(min.)
- Trigger LED current: 10mA(max.)
- On-state current: 0.6Arms(max.)
- Isolation voltage: 2500 V_{rms}(min.)
- UL recognized: UL1577, file no. E67349
- Trigger LED current

Classi– fication*	Trigger LED Current (mA) $V_T = 6V, Ta = 25^{\circ}C$		Marking Of	
	Min.	Max.	 Classification 	
(IFT5)	—	5.0	T5	
(IFT7)	—	7.0	T5, T7	
Standard	_	10	T5, T7, blank	

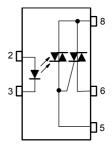
*Ex. (IFT5); TLP3502A(IFT5)

(Note) Application type name for certification test, please use standard product type name, i.e. TLP3502A (IFT5): TLP3502A



Weight: 0.52g

Pin Configuration (top view)



2 : Anode

- 3 : Cathode 5 : Triac gate
- 6 : Triac T1
- 8 : Triac T2

Unit in mm

Maximum Ratings (Ta = 25°C)

Characteristic			Symbol	Rating	Unit
	Forward current	١ _F	50	mA	
	Forward current derating (Ta ≥	ΔI _F / °C	-0.7	mA / °C	
LED	Peak forward current (100µs pu	ulse, 100pps)	I _{FP}	1	А
	Reverse voltage	V _R	5	V	
	Junction temperature	Tj	125	°C	
	Off-state output terminal voltage	V _{DRM}	400	V	
	On-state RMS current	Ta = 40°C		0.6	А
Detector		Ta = 60°C	I _{T(RMS)}	0.45	~
	On–state current derating (Ta ≥	ΔI _T / °C	-7.5	mA / °C	
	Peak current from snubber circ (100µs pulse, 120pps)	I _{SP}	2	А	
	Peak nonrepetitive surge current	I _{TSM}	5	А	
	Junction temperature	Tj	120	°C	
Storage temperature range			T _{stg}	-40~125	°C
Operating temperature range		T _{opr}	-20~80	°C	
Lead soldering temperature (10s)			T _{sol}	260	°C
Isolation voltage (AC, 1min., R.H.≤ 60%) (Note)			BVS	2500	V _{rms}

(Note) Device considered a two terminal: LED side pins shorted together and Detector side pins shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	V _{AC}	-		120	V _{ac}
Forward current	١ _F	15	20	25	mA
Peak current from snubber circuit	I _{SP}	_	_	1	A
Operating temperature	T _{opr}	-20		80	°C

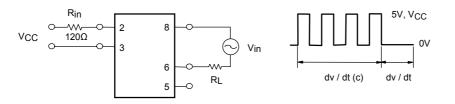
Individual Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min.	Тур.	Max.	Unit
LED	Forward voltage	VF	I _F = 10mA	1.0	1.15	1.3	V
	Reverse current	I _R	V _R = 5V		_	10	μA
	Capacitance	CT	V = 0, f = 1MHz		30	-	pF
Detector	Peak off-state current	I _{DRM}	V _{DRM} = 400V, Ta = 110°C	—	_	100	μA
	Peak on-state voltage	V _{TM}	I _{TM} = 0.75A	—	_	3.0	V
	Holding current	Ι _Η	—	—	_	25	mA
	Critical rate of rise of off–state voltage	dv / dt	V _{in} = 120V _{rms} (Fig.1) 200	500	_	V / µs
	Critical rate of rise of commutating voltage	dv / dt (C)	V_{in} = 120 V_{rms} , I _T = 0.5 A_{rms} (Fig.1) –	5	_	V / µs

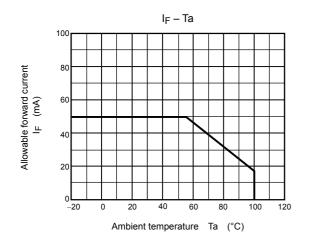
Coupled Electrical Characteristics (Ta = 25°C)

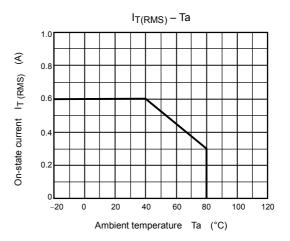
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit	
Trigger LED current	I _{FT}	V _T = 6V	_	_	10	mA	
Capacitance (input to output)	CS	V _S = 0, f = 1MHz		1.5	_	pF	
Isolation resistance	R _S	V _S = 500V	5×10 ¹⁰	10 ¹⁴	_	Ω	
	BV _S	AC, 1 minute	2500	_	_	V	
Isolation voltage		AC, 1 second, in oil	_	5000	—	V _{rms}	
		DC, 1 minute, in oil	-	5000	—	V _{dc}	

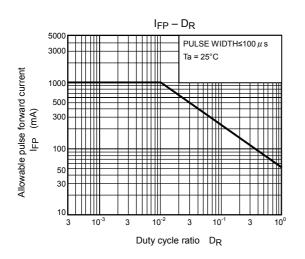
Fig.1: dv / dt test circuit

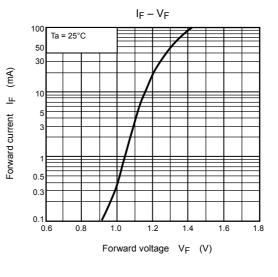


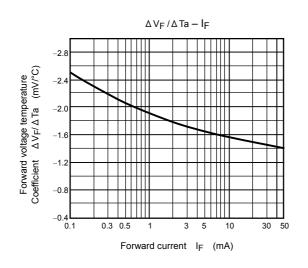
TOSHIBA



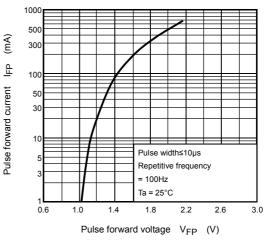








IFP – VFP



10³

10

10

10

0

20

40

60

Peak off-state current IDRM (arbitrary unit)

VDRM = Rated

60

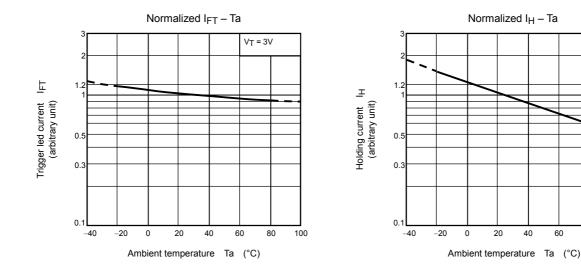
80

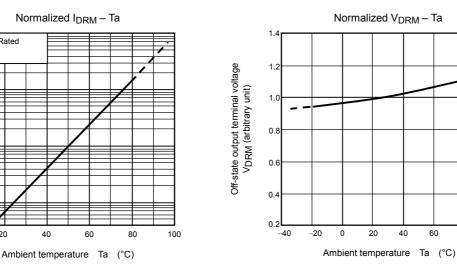
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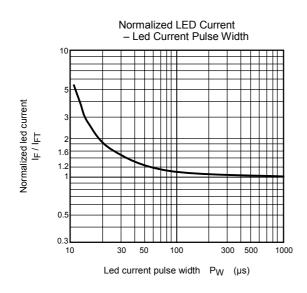
80

100

100







Normalized I_{DRM} – Ta

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000707EBC

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